Preliminary GaN Solid State Power Amplifier

RIM251K6-20

RFHIC

Product Features

- 2400 ~ 2500MHz (ISM band)
- 1600W CW Peak Power @ 50V
- 53% Drain Efficiency @ 50V
- Low Cost, Light Weight, Compact
- Using GaN-on-SiC HEMT Transistor
- Excellent Thermal Stability and Ruggedness
- Externally 50Ω Matched

Applications

- High Power Industry
- Microwave CVD Reactor
- Plasma Generator
- Food Science
- MW Heating and Drying



Description

RIM251K6-20 using GaN-on-SiC transistors is designed for industrial, scientific, medical (ISM) and plasma applications at 2450MHz. RIM251K6-20 is the world's highest power and efficiency SSPA with affordable price. This amplifier is suitable for use in CW, ISM applications. This high efficiency rugged device is targeted to replace industrial magnetrons and other vacuum tubes which are currently applying into high power industrial applications, artificial diamond manufacturing, semiconductor equipments, and plasma systems.

Electrical Specifications @ V_{DS} =50V, T=25°C, 50Ω System

P.	ARAMETER	UNIT	MIN	ТҮР	MAX	SYMBOL
Operating Frequency		MHz	2400	- (2500	Fo
Operating Bandwidth		MHz	-	100	-	OBW
CW Output Power		W	-	1600		Ро
Efficiency		%	-	53	-	Eff
]	Input Power		-	-6	-	PI
Power (Power Gain @ Peak Power		rfhi	68		Gp
(Gain Flatness		-	1.5	2.0	ΔG_P
In	Input Return Loss		-	-	-15	S_{11}
Operating Voltage		V	-	50		Vdc
Operating Case Temperature		-	5	-	60	Tc
	VDC(+50V)	A1, A2	50V ±1%			-
	Reverse Detection	1	<4.5V			-
DC & Controls Connector Pinmap (7W2)	Forward Detection	2	<4.5V			-
	N.C	3				-
	Temp. Monitor (LM50)	4	Temp °C= (Vout - 500 mV) x °C/10 mV			-
	Enable(H)/ Disable(L)	5	A voltage on the operation. Force	-		

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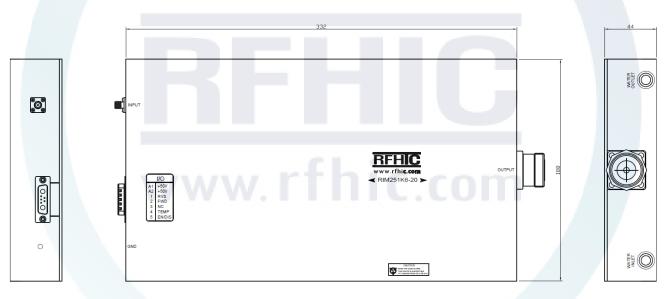
Mechanical Specifications

PARAMETER	UNIT	VALUE	
Dimensions (L x W x H)	mm	332 x 188 x 44	
Weight	Kg	4.6	
RF Input Connectors	-	SMA, Female	
RF Output Connectors	-	7/16 DIN, Femail	
DC & I/O Connector	-	D-sub 7W2	
Cooling	-	Water cooling (Water pressure: 8Bar)	

Note

Dimensions and Connectors may be subject to change.

Mechanical drawing



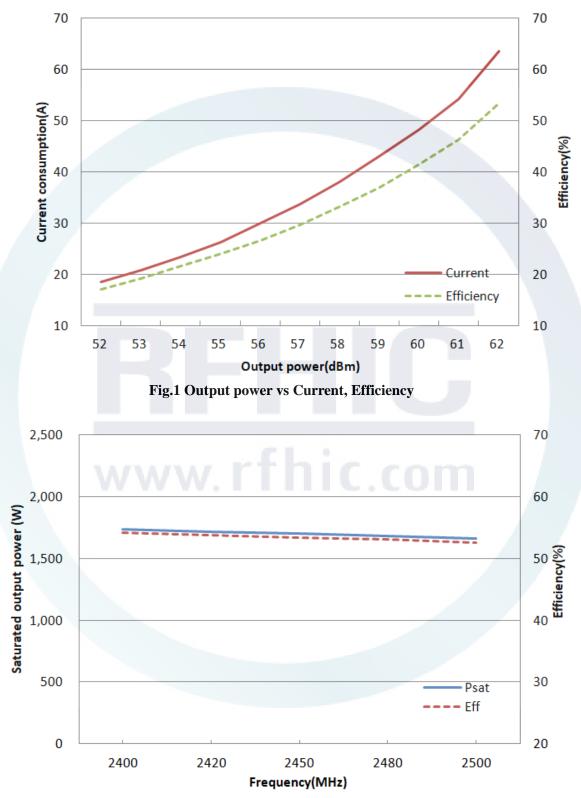
Note

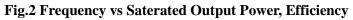
Connector positions and module mount holes may be subject to change.

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Performance Charts





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Revision History

Part Number Release Date		Version	Description	Data Sheet Status	
RIM251K6-20	May, 2018	0.1	Initial release of datasheet	Preliminary	



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